**Vishay Semiconductors** 

## **Three Phase Bridge** (Power Modules), 90 A/110 A



www.vishay.com

PRIMARY CHARACTERISTICS			
Ι <sub>ο</sub>	90 A to 110 A		
V <sub>RRM</sub>	800 V to 1600 V		
Package	MTK		
Circuit configuration	Three phase bridge		

### **FEATURES**

· Package fully compatible with the industry standard INT-A-PAK power modules series



COMPLIANT

- High thermal conductivity package, electrically insulated case
- · Excellent power volume ratio, outline for easy connections to power transistor and IGBT modules
- 4000 V<sub>RMS</sub> isolating voltage
- UL E78996 approved
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### DESCRIPTION

A range of extremely compact, encapsulated three phase bridge rectifiers offering efficient and reliable operation. They are intended for use in general purpose and heavy duty applications.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES 90MT.K	VALUES 110MT.K	UNITS	
1		90 (120)	110 (150)	A	
IO	T <sub>C</sub>	90 (61)	90 (57)	°C	
1	50 Hz	770	950	٨	
IFSM	60 Hz	810	1000	A	
l <sup>2</sup> t	50 Hz	3000	4500	A <sup>2</sup> s	
1-1	60 Hz	2700	4100	A-S	
l²√t		30 000	45 000	A²√s	
V <sub>RRM</sub>	Range	800 to 1600		V	
T <sub>Stg</sub>	Panga	-40 to 150		- °C	
TJ	Range	-40 to 150			

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> MAXIMUM AT T <sub>J</sub> = MAXIMUM mA	
VS-90MTK VS-110MTK	80	800	900		
	100	1000	1100		
	120	1200	1300	10	
	140	1400	1500		
	160	1600	1700		

Revision: 17-Aug-17 Document Number: 94352 1 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



Vishay Semiconductors

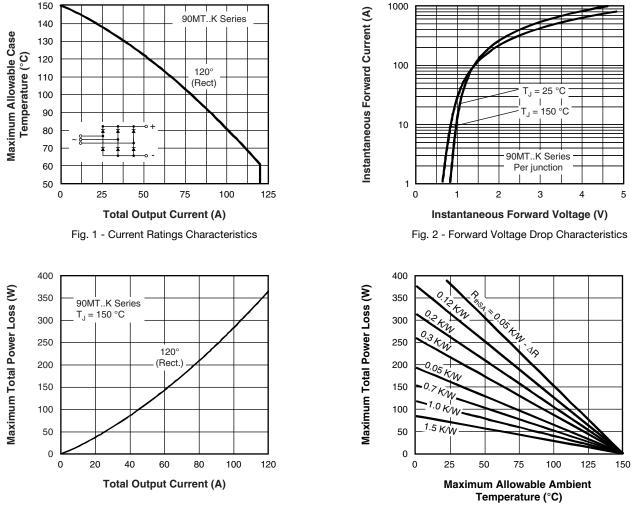
### FORWARD CONDUCTION

PARAMETER	SYMBOL	TEST CONDITIONS		VALUES 90MT.K	VALUES 110MT.K	UNITS	
Maximum DC output current at case temperature	Ι <sub>Ο</sub>	120° rect. conduction angle		90 (120) 90 (61)	110 (150) 90 (57)	A °C	
	+	t = 10 ms	Newskewe		770	950	A
Maximum peak, one-cycle forward, non-repetitive surge current		t = 8.3 ms	No voltage reapplied		810	1000	
	I <sub>FSM</sub>	t = 0.0  ms	100 % V <sub>BBM</sub>	Initial	650	800	
		t = 8.3  ms	reapplied		680	840	
	t = 10 ms t = 8.3 ms reapplied	$T_J = T_J$ maximum	3000	4500			
Maximum I <sup>2</sup> t for fusing		t = 8.3 ms		0 0	2700	4100	A <sup>2</sup> s
		t = 10 ms	100 % Voou		2100	3200	
		t = 8.3 ms			1900	2900	
Maximum I <sup>2</sup> $\sqrt{t}$ for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied		30 000	45 000	A²√s	
Low level value of threshold voltage	V <sub>F(TO)1</sub>	(16.7 % x $\pi$ x $I_{F(AV)} < I < \pi$ x $I_{F(AV)}$ ), $T_J$ maximum		0.89	0.81	v	
High level value of threshold voltage	V <sub>F(TO)2</sub>	$(I > \pi \times I_{F(AV)}), T_J$ maximum		1.05	0.99		
Low level value of forward slope resistance	r <sub>f1</sub>	(16.7 % x $\pi$ x $I_{F(AV)} < I < \pi$ x $I_{F(AV)}$ ), T <sub>J</sub> maximum			5.11	4.37	mΩ
High level value of forward slope resistance	r <sub>f2</sub>	$(I > \pi \times I_{F(AV)}), T_J$ maximum			4	.64	1115.2
Maximum forward voltage drop	V <sub>FM</sub>	$I_{pk} = 150 \text{ A}, T_J = 25 \text{ °C}$ $t_p = 400  \mu \text{s} \text{ single junction}$			1.6	1.4	v
RMS isolation voltage	V <sub>ISOL</sub>	$T_J = 25 \text{ °C}$ , all terminal shorted f = 50 Hz, t = 1 s			40	000	

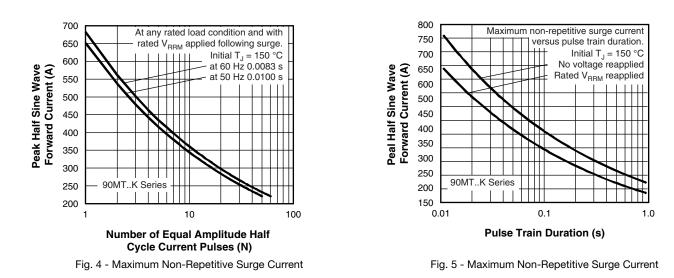
THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES 90MT.K	VALUES 110MT.K	UNITS	
Maximum junction operating and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-40 to 150		°C	
Maximum thermal resistance, junction to case		DC operation per module	0.21	0.18		
	В	DC operation per junction	1.26	1.07		
	R <sub>thJC</sub>	120° rect. conduction angle per module	0.25	0.21	°C/W	
		120° rect. conduction angle per junction	1.47	1.25		
Maximum thermal resistance, case to heatsink per module	R <sub>thCS</sub>	Mounting surface smooth, flat and greased	0.03			
Mounting to heatsink		A mounting compound is recommended and the 4 to 6		to 6	Nm	
torque ± 10 % to termina		torque should be rechecked after a period of 3 h to allow for the spread of the compound.		3 to 4		
Approximate weight		Lubricated threads.	1	76	g	



**Vishay Semiconductors** 







Revision: 17-Aug-17

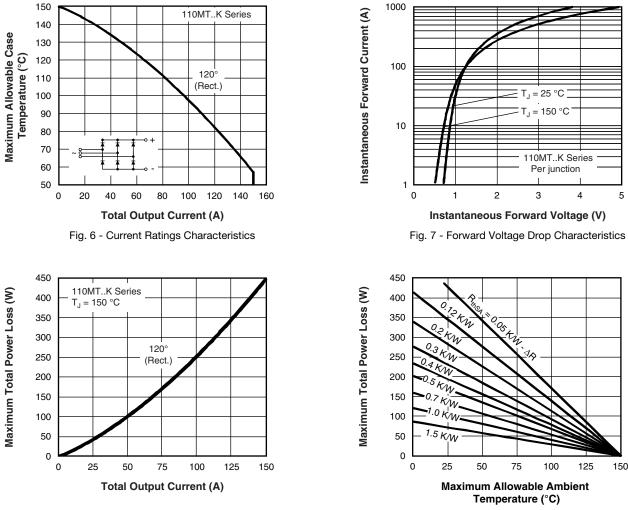
3

Document Number: 94352

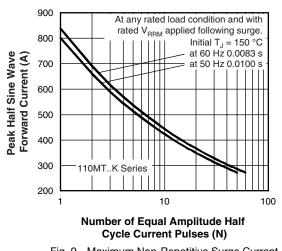
For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



**Vishay Semiconductors** 









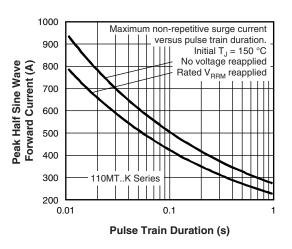


Fig. 10 - Maximum Non-Repetitive Surge Current

Revision: 17-Aug-17

4

Document Number: 94352

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



**Vishay Semiconductors** 

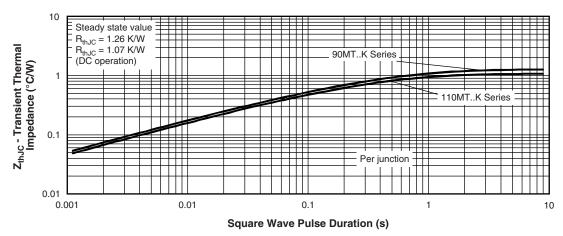
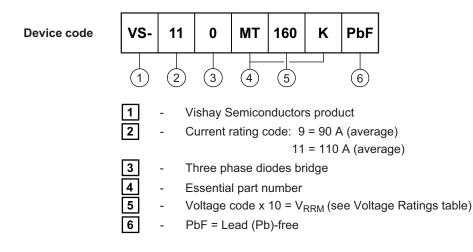


Fig. 11 - Thermal Impedance Z<sub>thJC</sub> Characteristic

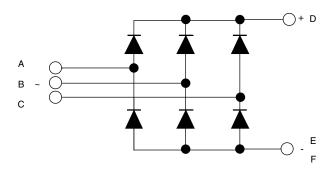
### **ORDERING INFORMATION TABLE**



#### Note

• To order the optional hardware go to <u>www.vishay.com/doc?95172</u>

#### **CIRCUIT CONFIGURATION**



LINKS TO RELATED DOCUMENTS					
Dimensions		www.vishay.com/doc?95004			
Revision: 17-Aug-17	5	Document Number: 94352			

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

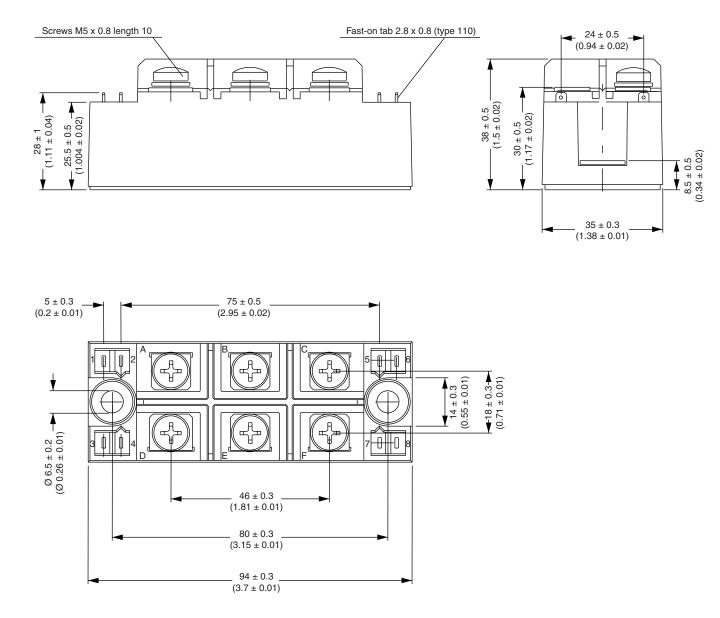


**Vishay Semiconductors** 

# MTK (with and without optional barrier)

### **DIMENSIONS WITH OPTIONAL BARRIERS** in millimeters (inches)

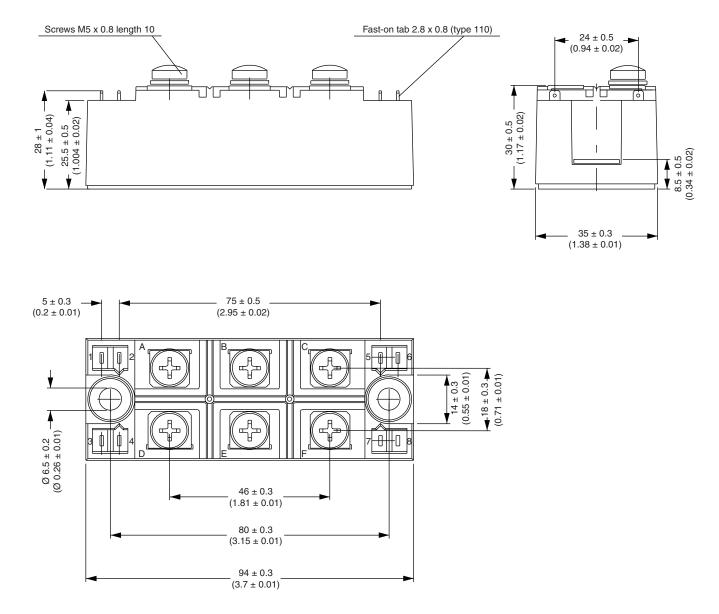
SHAY



Vishay Semiconductors MTK (with and without optional barrier)



### DIMENSIONS WITHOUT OPTIONAL BARRIERS in millimeters (inches)





Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.